

Supplementary Information

A highly stable, selective, and high-performance VOC sensor using a SnS₂ nano-lotus structure

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Fig. S1: Optical image of SnS₂ NLS gas sensor.

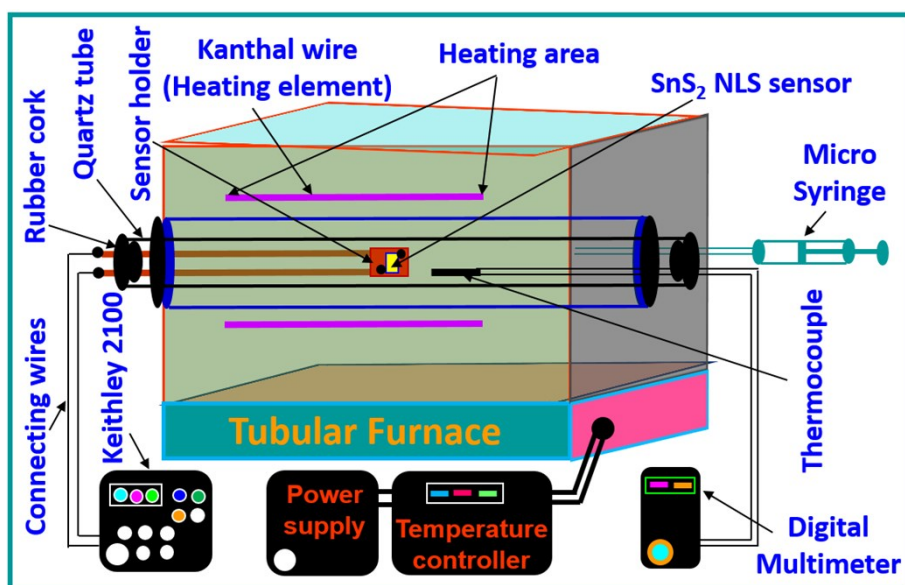


Fig. S2: Schematic view of gas sensing experimental setup.

The volume (V_{VOCs}) of liquid VOCs (μL) are calculated at a particular operating temperature and concentration (ppm) by using the following Eq. S1,¹

$$V_{VOCs} (\mu L) = \frac{M_{VOCs} C_{ppm} PV}{\rho_{VOCs} RT} \quad (S1)$$

where M_{VOCs} , C_{ppm} , P , V , ρ_{VOCs} , R , and T are the molar mass, VOCs concentration, pressure, test chamber volume, the density of VOCs, the universal gas constant, and operating temperature, respectively.

The lattice spacing corresponding to an individual lattice of SnS₂ nano-lotus system (NLS) was calculated using Bragg's diffraction formula as discussed in Eq. S2,^{2,3}

$$2d \sin \theta = n\lambda \quad (S2)$$

where d is lattice spacing (interplanar spacing), θ is Bragg's diffraction angle, n ($= 1$), λ is the wavelength of X-ray diffraction (here, Cu $k_{\alpha} = 1.54056 \text{ \AA}$).

The lattice strain (ε) of SnS₂ NLS were evaluated using Eq. S3 (Tangent formula), respectively.^{2,3}

$$\varepsilon = \frac{\beta}{4 \tan \theta} \quad (S3)$$

where β and θ are the lattice spacing, X-ray wavelength, full width at the half maximum of the diffraction peaks, and Bragg's diffraction angle.

Table S1: Analysis of XRD results of the SnS₂ nano-lotus structure (NLS).

XRD analysis using experimental results					Lattice parameters using Rietveld refinement	JCPDS data 23-0677	
S. No.	2 θ (°)	Lattice planes (<i>hkl</i>)	Lattice spacing (<i>d</i> , nm)	Lattice strain (ϵ)		Lattice spacing (<i>d</i> , nm)	Lattice parameters
1	15.0405	(001)	0.5885	0.0127	a (= b) = 3.6438 Å c = 5.9038 Å c/a = 1.6202	0.5890	a (= b) = 3.6486 Å c = 5.8992 Å c/a = 1.6168
2	28.3177	(100)	0.3148	0.0037		0.3162	
3	32.2069	(101)	0.2777	0.0058		0.2784	
4	41.9489	(102)	0.2151	0.0061		0.2155	
5	50.0970	(110)	0.1819	0.0031		0.1824	
6	52.5956	(111)	0.1738	0.0041		0.1743	
7	55.0366	(103)	0.1667	0.0048		0.1669	
8	60.7859	(201)	0.1522	0.0037		0.1526	

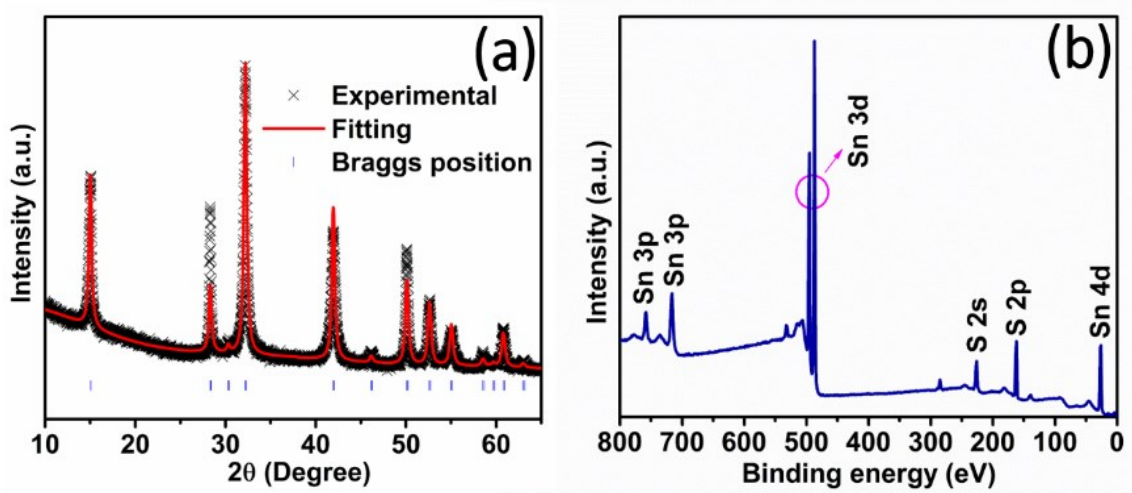


Fig. S3: (a) Rietveld refinement of XRD spectrum; and XPS survey spectrum of the SnS₂ NLS.

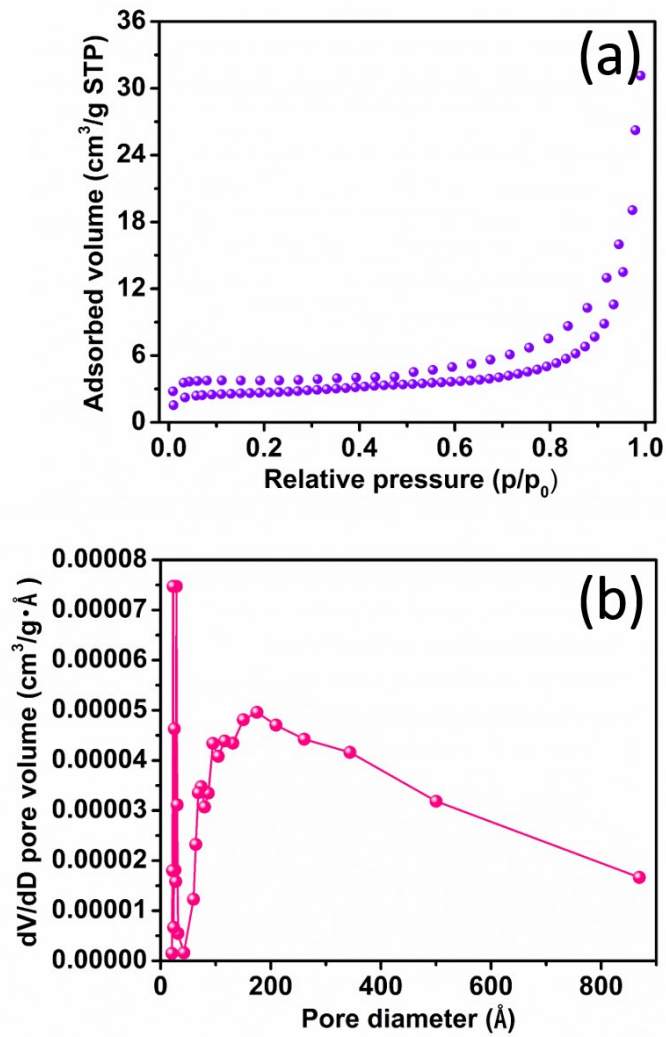


Fig. S4: (a) BET adsorbed volume vs. p/p_0 plot, (b) BJH dV/dD pore volume vs. pore diameter plot of SnS₂ NLS.

Table S2: BET surface area, BJH pore size, and volume analysis of SnS₂ NLS sensor.

	BET surface area	BJH pore size	BJH pore volume
lotus-like SnS ₂	10.2304 m ² /g	Adsorption	Adsorption
		32.3905 nm	0.0459 cm ³ /g

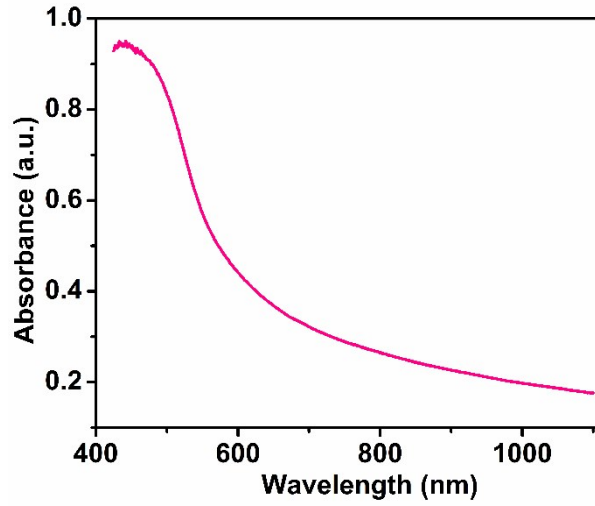


Fig. S5: UV-visible absorbance spectrum of SnS₂ NLS.

For the evaluation of energy bandgap by diffuse reflectance spectroscopy (DRS), the Kubelka-Munk equation is written in Eq. S4,^{4,5}

$$\frac{K}{S} = \frac{(1 - R)}{2R} = F(R) \quad (\text{S4})$$

where S , K , and R are the scatterings, absorption coefficients, and reflectance, respectively, and $F(R)$ is the Kubelka-Munk function. The optical bandgap and absorption coefficient α of a direct bandgap SnS₂ NLS are evaluated using the following Eq. S5,^{4,5}

$$\alpha h\nu = C_1(h\nu - E_g)^{1/2} \quad (\text{S5})$$

where α , $h\nu$, C_1 , and E_g are the linear absorption coefficient of the material, photon energy, a proportionality constant, and optical bandgap, respectively.

The Kubelka-Munk absorption coefficient S is constant with wavelength when lotus-like SnS_2 diffusely scatters light and using the Eq. S5, we obtain the expression as written in Eq. S6,^{4,5}

$$[F(R)h\nu]^2 = C_2(h\nu - E_g) \quad (\text{S6})$$

Thus, by using Eq. S4 & S6, we can easily calculate the optical bandgap of SnS_2 NLS.

The Urbach energy is evaluated by using the following Eq. S7,^{1,6}

$$\alpha = \alpha_o \exp\left(\frac{E}{E_U}\right) \quad (\text{S7})$$

By using the Eq. S4 and Eq. S7, we can deduce the following relation Eq. S8,

$$F(R) = F(R)_o \exp\left(\frac{E}{E_U}\right) \quad (\text{S8})$$

Therefore, we can easily estimate the Urbach energy of SnS_2 NLS using Eq. S8.

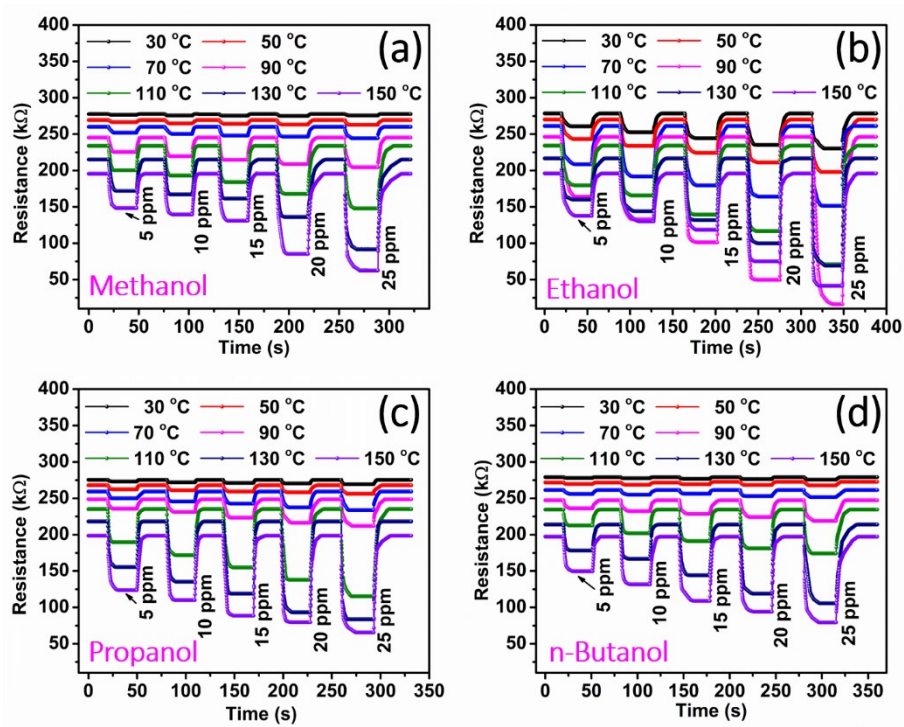


Fig. S6: (a-d) Dynamic gas sensing the resistance of SnS₂ NLS sensor to detect VOCs for various concentrations at different operating temperatures.

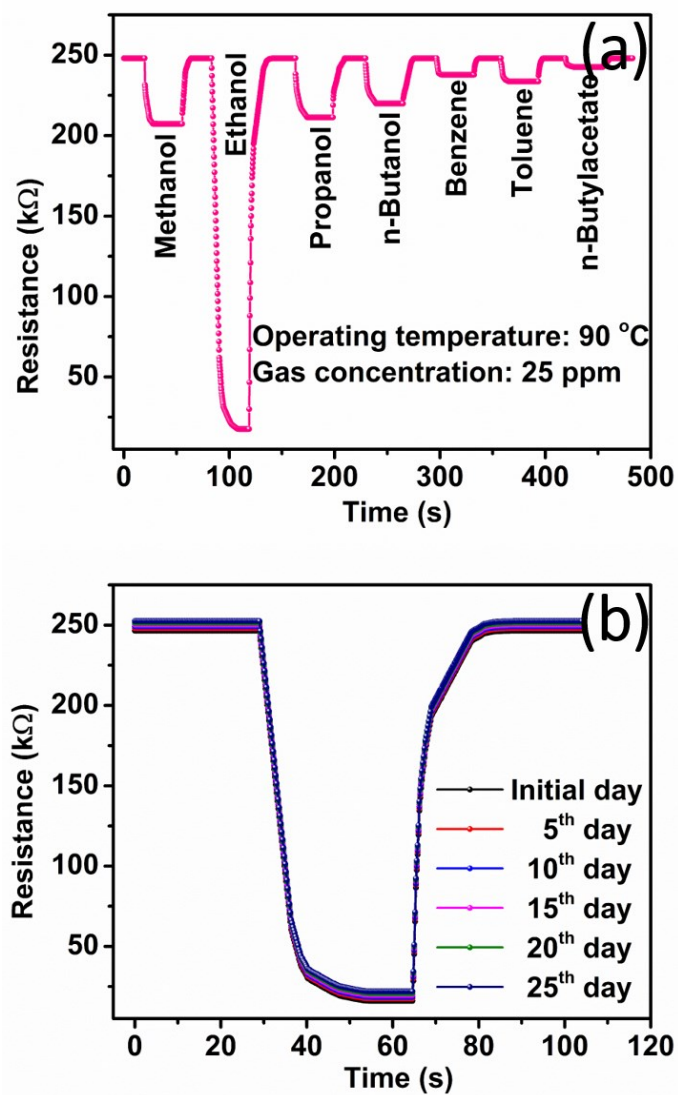


Fig. S7: Gas sensing resistance characteristics of SnS₂ NLS sensor; (a) selectivity for 25 ppm under various interfering gas at an operating temperature of 90 °C, and (b) stability test cycles for 25 ppm of ethanol concentration at 90 °C.

The selectivity coefficient of the SnS₂ NLS sensor was estimated by using the following Eq.

S9;⁷

$$S_c = \frac{S_{ethanol}}{S_{interfering\ gas}} \quad (S9)$$

where S_c and $S_{interfering\ gas}$ are the sensitivities of SnS₂ NLS sensor to ethanol and other interfering gas, respectively, as listed in Table S3.

Table S3: Analysis of the selectivity coefficient of SnS₂ NLS sensor for 25 ppm concentration at an optimum operating temperature of 90 °C.

Sensing Element	Interfering gas with 25 ppm concentration					
	Methanol	Propanol	n-Butanol	Benzene	Toluene	n-Butylacetate
lotus-like SnS ₂ based ethanol sensor	5.7	6.3	8.1	22.7	16.0	42.2

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